NSN 5961-00-422-5280

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-422-5280
Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Unijunction
Electrode Internally-electrically Connected To Case:
Base 2
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
3.0 base to emitter saturation voltage
Current Rating Per Characteristic:
50.00 milliamperes repetitive peak forward current megahertz
Power Rating Per Characteristic:
360.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pn
Precious Material And Location:
Terminal surface option gold
Precious Material:
Gold
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/388 government specification
Shelf Life:
N/a

--

Unit Of Measure:

NSN 5961-00-422-5280

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0